NSN 5961-01-414-9173

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-414-9173

Inclosure Material:
Plastic
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-236ab
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
12.0 collector to emitter voltage/static/base open and 20.0 collector to base voltage/static/emitter open and 2.5 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
50.00 milliamperes source cutoff current
Power Rating Per Characteristic:
350.0 milliwatts small-signal input power, common-collector preset
Terminal Type And Quantity:
3 bonding pad
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig:
A110a0